# **Supporting Information**

## Growth and NO<sub>2</sub> Sensing Properties of Biaxial p-SnO/n-ZnO Heterostructured

#### Nanowires

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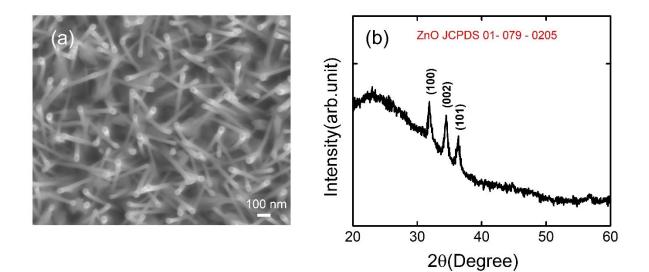
#### Experimental detail

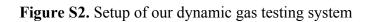
#### The synthesis of ZnO nanowires

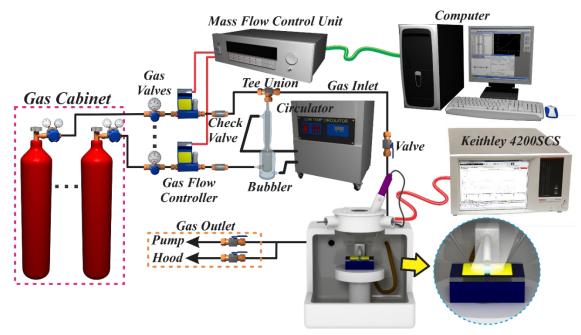
Without catalyzed ZnO nanowires were growth directly on the glass substrate via thermal oxidation process. The glass substrate is 20 cm away from the source which was mixed from active carbon and ZnO powder (both purities are 99.99%) in a 1:1 weight ratio. The source put in an alumina boat and was loaded at the center of a quartz tube. For synthesis of the ZnO nanowires, a conventional thermal chemical vapor deposition (CVD) process with mixed N<sub>2</sub>-O<sub>2</sub> gas (N<sub>2</sub>: 4 sccm, O<sub>2</sub>: 1 sccm) was used. The furnace was heated up to 950°C and the pressure in the processing tube was controlled at 2 x 10<sup>-2</sup>Torr. After the quartz tube was evacuated to ~ 5 x 10<sup>-3</sup>Torr, the furnace temperature was increased from room temperature to 950°C. When the temperature increased up to growth temperature (950°C), a mixed N<sub>2</sub>-O<sub>2</sub> gas (N<sub>2</sub>: 4 sccm, O<sub>2</sub>: 1 sccm) was provided as the reaction gas. While introducing the reaction gas, the pressure of the system was maintained at 2 x 10<sup>-2</sup>Torr and the temperature of 450 °C. After the reaction, the furnace was naturally cooled down to room temperature and the ZnO ranowires were collected on the glass substrate.

Figure S1 shown the FE-SEM image and XRD pattern of as-synthesized ZnO nanowire on the glass substrate.

**Figure S1.** (a) FE-SEM image, (b) XRD pattern of as-synthesized ZnO nanowire on the glass substrate







**Testing Chamber**